

Integrated photonic coupled Sagnac loop reflector filters for flat-top wavelength interleaving and switching

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Abstract

We investigate integrated photonic resonators formed by coupled Sagnac loop reflectors (CSLR). Mode splitting in the CSLR resonator is tailored to provide flat-top spectral response for wavelength interleaving and non-blocking switching functions in C band.

Integrated photonic coupled Sagnac loop reflector filters for flat-top wavelength interleaving and switching

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Abstract: We investigate integrated photonic resonators formed by coupled Sagnac loop reflectors (CSLR). Mode splitting in the CSLR resonator is tailored to provide flat-top spectral response for wavelength interleaving and non-blocking switching functions in C band.

1. Introduction

Optical interleavers performing signal multiplexing / demultiplexing both at the transmitters and receivers as well as optical switching nodes performing signal routing among a set of input and output ports are core components in wavelength division multiplexing (WDM) optical communication systems [1, 2]. The capability to realize these devices in the form of photonic integrated circuits will reap the great dividends including compact footprint, low energy consumption, high scalability and the potential to significantly reduce cost by mass production [3, 4]. In WDM systems, optical interleavers and switching nodes with a flat-top spectral response that can minimize filtering distortions are highly desirable. To date, various schemes have been demonstrated to realize integrated optical interleavers and switching nodes [2, 5-8]. However, these devices, based on either finite-impulse-response (FIR) filters such as Mach-Zehnder interferometers (MZIs) or infinite-impulse-response (IIR) filters such as Fabry-Perot (FP) or Gires-Tournois (GT) [9-13] cavities and microring resonators, suffer from a fundamental limitation in terms of filter shape that allows them to achieve flat-top spectral responses only by cascading many subunits. This imposes stringent requirements for the alignment of resonant wavelengths from separate subunits and limits the practical applications out of laboratory.

Recently [14, 15], we reported devices in silicon-on-insulator (SOI) nanowires formed by Sagnac loop reflectors (SLRs). Here, we theoretically investigate more advanced filter structures using similar principles. We tailor mode splitting in a resonator formed by two coupled Sagnac loop reflectors (CSLR) consisting of both FIR and IIR filter elements to achieve wavelength interleaving and non-blocking switching functions with flat-top spectral response. Other requirements for practical WDM systems including high extinction ratio (ER), low insertion loss (IL), low crosstalk and channel spacing (CS) meeting the ITU-T standards [16] are also considered in our design and achieved for the proposed device. These results highlight the strong potential of using CSLR resonators to achieve wavelength interleaving and non-blocking switching in WDM systems.

2. Device configuration and operation principle

Figure 1(a) shows the schematic of the proposed CSLR resonator, which consists of two parallel SLRs coupled to a top bus waveguide. The two SLRs are identical and each SLR is formed by a self-coupled SOI nanowire with a length of L_{SLR} . Here, t_1 and κ_1 are the field transmission and cross coupling coefficients of the directional couplers in the SLRs, respectively, while t_2 and κ_2 are the field transmission and cross coupling coefficients of the directional couplers formed by the SLRs and the top bus waveguide, respectively. L_i ($i = 1, 2$) are the lengths of the top and bottom connecting waveguides between the two SLRs. For the SOI nanowire with a cross section of $500 \text{ nm} \times 260 \text{ nm}$, we use a waveguide group index for TE polarization of $n_g = 4.3350$ and a propagation loss of $\alpha = 55 \text{ m}^{-1}$ (i.e., 2.4 dB/cm) based on our fabricated devices [14, 15]. The CSLR resonator is equivalent to an MZI and an FP cavity when $t_1 = 1$ and $t_2 = 1$, respectively. When $t_1 \neq 1$ and $t_2 \neq 1$, it can be regarded as a hybrid filter consisting of both FIR and IIR filter elements. The mutual interaction between the FIR and IIR filter elements yields efficient coherent optical mode interference, which allows a flat-top spectral response for a device with only two SLRs. The transmission spectra of the CSLR resonator can be tailored by changing t_1 and t_2 , which enables flexible spectral engineering with the CSLR resonator for many filtering functions.

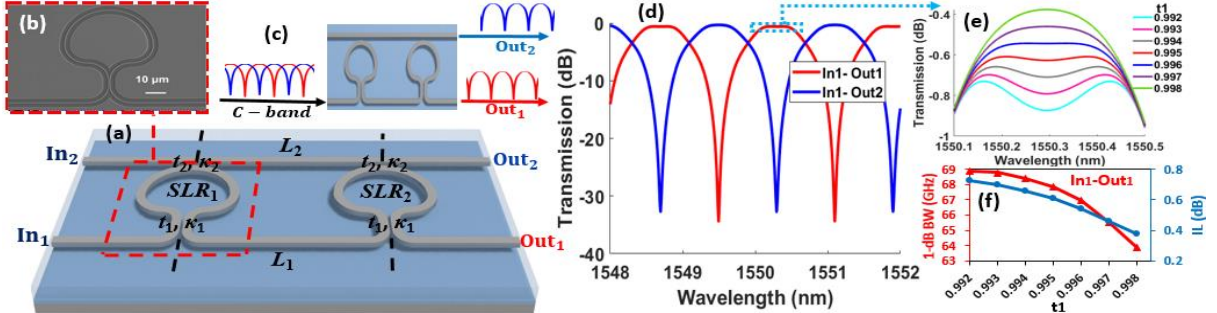


Fig. 1. (a) Schematic configuration of the proposed CSLR resonator. (b) SEM image of the fabricated SLR on an SOI wafer. (c) Interleaving operation based on the device in (a). (d) Output spectra at port Out₁ and Out₂ with input from port In₁. (e) Filter shapes of the output spectra at port Out₁ for different t_1 . (f) 1-dB bandwidth and insertion loss versus t_1 .

The scanning electron microscope (SEM) image of a fabricated SLR is shown in Fig. 1(b). The interleaving operation based on the CSLR resonator is shown in Fig. 1(c). Figure 1(d) shows the power transmission spectra calculated based on the scattering matrix method [14, 15] with input from port In_1 . The structural parameters ($L_{SLR1,2} = L_{1,2} = 346 \mu\text{m}$, $t_1 = 0.995$, $t_2 = 0.707$) are designed for achieving a CS of about 100 GHz in C band to meet the ITU-T spectral grid standards G694.1. Figure 1(e) shows the filter shapes of the output spectra at port Out_1 for different t_1 . The calculated 1-dB bandwidth (BW) and IL as functions of t_1 are depicted in Fig. 1(f). Table 1 compares the 0.5-dB and 1-dB BWs, ERs and ILs of the MZI (when $t_1 = 1$) and the CSLR resonators with input from different ports (In_1 and In_2). As compared with the MZI, the CSLR resonator shows a significantly improved top flatness at the expense of slightly reduced ERs and ILs within reasonable ranges.

Table 1. Performance comparison of the interleavers based on MZI and CSLR resonators.

	MZI ($t_1=1$)		CSLR resonator with input port from In_1		CSLR resonator with input port from In_2	
	Out_1	Out_2	Out_1	Out_2	Out_1	Out_2
0.5-dB BW (GHz)	42.7688	42.7852	56.1612	44.4834	46.6557	45.9546
1-dB BW (GHz)	59.9887	59.9767	67.8828	60.8639	60.9014	60.6391
ER (dB)	45.9179	46.4525	33.7906	32.3885	32.3885	30.9091
IL (dB)	0.2065	0.1652	0.6083	0.3341	0.3341	0.2068
CS (GHz)	100.0053		100.0053		100.0053	

We also design 2×2 non-blocking switching unit based on the CSLR resonator. Figure 2(a) shows the zoom-in view of Fig. 1(d). For comparison, the transmission spectra from In_2 to Out_1 and Out_2 in the same wavelength range are depicted in Fig. 2(b). Two wavelength channels centered at $\lambda_1 = 1549.4938 \text{ nm}$ and $\lambda_2 = 1550.29456 \text{ nm}$ are selected for the operation of the cross (Fig. 2(c)) and bar (Fig. 2(d)) states, respectively. When λ_1 is red shifted to λ_2 via thermo-optic effect, the switching unit changes from cross state to bar state. The calculated ERs, ILs and crosstalk are shown in Table 2. As can be seen, flat-top spectral response with high ERs, low ILs and low crosstalk are achieved. When input port is changed to In_2 , the wavelength channels for the cross and bar states remain unchanged, i.e., $\lambda_1 = \lambda_1'$ and $\lambda_2 = \lambda_2'$.

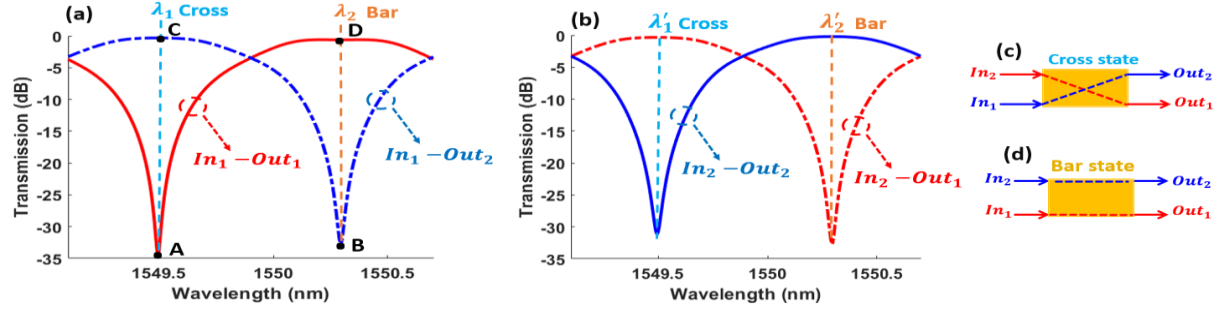


Fig. 2. (a) Zoom-in view of Fig. 1(d) in the wavelength range of 1549.1 nm – 1550.7 nm. (b) Output spectra at port Out_1 and Out_2 with input only from port In_2 . (c)–(d) Schematics showing the cross and bar states of the non-blocking switching unit, respectively.

Table 2. Performance of the non-blocking switching unit based on CSLR resonator.

Operation state	Cross	Bar
Operation wavelength (nm)	$\lambda_1 = \lambda_1' = 1549.4938$	$\lambda_2 = \lambda_2' = 1550.2945$
Extinction ratio (dB)	$P_C - P_B = 32.3885$	$P_D - P_A = 33.7906$
Crosstalk (dB)	$P_A - P_C = -34.0669$	$P_B - P_D = -32.1142$
Insertion loss (dB)	0.3341	0.6083

4. Conclusions

We theoretically investigate wavelength interleaving and non-blocking switching based on integrated CSLR resonator. Flat-top spectral responses are achieved by tailoring mode splitting in the CSLR resonator.

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